# UC Irvine UC Irvine Previously Published Works

### Title

Superconductivity of single-crystal NbGe2

### Permalink

https://escholarship.org/uc/item/90f6t78h

### Journal

Journal of the Less Common Metals, 62(NOV-)

### ISSN

0022-5088

### Authors

Remeika, JP Cooper, AS Fisk, Z <u>et al.</u>

#### **Publication Date**

1978-11-01

## DOI

10.1016/0022-5088(78)90033-4

## **Copyright Information**

This work is made available under the terms of a Creative Commons Attribution License, available at <u>https://creativecommons.org/licenses/by/4.0/</u>

Peer reviewed

#### SUPERCONDUCTIVITY OF SINGLE-CRYSTAL NbGe<sub>2</sub>\*

J. P. REMEIKA and A. S. COOPER

Bell Laboratories, Murray Hill, N. J. 07974 (U.S.A.)

Z. FISK and D. C. JOHNSTON

Institute for Pure and Applied Physical Sciences, University of California, San Diego, La Jolla, Calif. 92093 (U.S.A.)

(Received July 17, 1978)

#### Summary

Small single crystals of  $NbGe_2$  were grown by the hydrogen reduction of potassium-containing oxides. Measurements of electrical resistivity and superconductivity are given.

Matthias *et al.* [1] were the first to show that the A15 compound Nb<sub>3</sub>Ge was a high transition temperature superconductor. Subsequent to the work of Gavaler [2] and later Testardi *et al.* [3] which pushed the  $T_c$  of Nb<sub>3</sub>Ge to 23 K, Ghosh and Douglas [4] reported superconductivity to 16 K in sputtered films containing Ge and NbGe<sub>2</sub>. It appeared that the Ge-rich portion of the Nb–Ge phase diagram might also be interesting from the standpoint of superconductivity, especially since Hardy and Hulm [5] found the C40 compound NbGe<sub>2</sub> to be normal to 1.2 K. The sputtering target used in ref. 4 had  $T_c = 1.85$  K.

The work described here is based on the observation that  $KNbO_3$  could be reduced to Nb metal in H<sub>2</sub> at relatively low temperatures. This suggested the possible production at relatively low temperature of Nb<sub>3</sub>Ge by hydrogen reduction of  $KNbO_3$  and  $K_2GeO_3$  mixtures with a Nb:Ge ratio of 3:1. These mixtures were made both by ball milling the crushed oxides and by reaction of  $K_2CO_3$  with a Nb<sub>2</sub>O<sub>5</sub>-GeO<sub>2</sub> mixture.

Hydrogen reduction was carried out overnight at temperatures in the range 800 - 1100 °C with little variation in the result. The mass that resulted from this reduction was interspersed with small columnar metallic crystals (typically 0.5 mm  $\times$  0.05 mm  $\times$  0.05 mm). A measurement of superconductivity on the entire product gave an incomplete transition with  $T_{\rm c}$  onset of 2.0 K.

X-ray analysis of these crystals showed them to be NbGe<sub>2</sub> with lattice parameters  $a_0 = 4.965$  Å,  $c_0 = 6.783$  Å. A quantity of these crystals was isolated, crushed and found to have a  $T_c$  onset of 2.1 K and width 0.4 K. It

<sup>\*</sup>Dedicated to Professor B. T. Matthias in celebration of his 60th birthday.

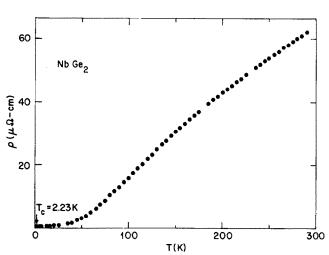


Fig. 1. Temperature-dependent electrical resistivity of an NbGe<sub>2</sub> single crystal. A similar crystal was found to have growth axis  $\langle 11\bar{2}0\rangle$ , and this is quite probably the direction measured here.

is likely, therefore, that the  $T_c$  seen in the bulk reduction mass is due to NbGe<sub>2</sub>. A four-probe electrical resistivity measurement on one of these crystals (Fig. 1) gave  $T_c = 2.23 \pm 0.03$  K. The resistance ratio to 4.2 K for this crystal is 100, the room temperature resistivity is  $60 \pm 15 \mu\Omega$  cm. An X-ray rotation photograph of one of the crystals showed that its growth axis was  $\langle 11\overline{2}0 \rangle$ .

This result was compared with arc-melted samples at nominal compositions NbGe<sub>2</sub> and NbGe<sub>5</sub>, annealed at 950 °C for one week. The NbGe<sub>2</sub> sample had  $T_c = 2.09 \pm 0.02$  K and for the NbGe<sub>5</sub> sample  $T_c = 2.16 \pm 0.01$  K. This last sample reacted somewhat with its protective Ta wrapper, possibly influencing the  $T_c$ . Nothing in the a.c. susceptibility was observed at higher temperature in either of these samples.

By varying the ratio of Nb:Ge in the initial mixture of oxides we were unable to produce material with a higher transition temperature. The actual mechanism for the growth of the NbGe<sub>2</sub> crystals is not clear. The possibilities include vapor growth and growth from KOH flux. It would be interesting to investigate this last possibility, but the container problem for molten KOH under these conditions is severe.

It is interesting that the hydrogen reduction of these oxides proceeds so readily, apparently due to the presence of potassium. This reduction technique might prove useful in the low temperature synthesis of a number of other intermetallics.

#### Acknowledgments

This work done at U.C., S.D., was supported by the National Science Foundation under Grant Numbers NSF/DMR77-08469 and NSF/DMR77-23774. We are indebted to H. Barz for some of the measurements of superconductivity.

#### References

- 1 B. T. Matthias, T. H. Geballe, R. H. Willens, E. Corenzwit and G. W. Hull, Jr., Phys. Rev. A, 139 (1965) 142.
- 2 J. R. Gavaler, Appl. Phys. Lett., 23 (1973) 480.
- 3 L. R. Testardi, J. H. Wernick and W. A. Royer, Solid State Commun., 15 (1974) 1.
- 4 A. K. Ghosh and D. H. Douglas, Superconductivity in d- and f-Band Metals, Plenum Press, New York, 1976, p. 59.
- 5 G. F. Hardy and J. K. Hulm, Phys. Rev., 93 (1954) 1004.